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**Whitbread et al.**

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(54) **OPTICAL AUTOCORRELATOR**

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EP 0 971 500 A 1/2000

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(21) Appl. No.: **10/399,085**

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(57) **ABSTRACT**

(30) **Foreign Application Priority Data**

Oct. 12, 2000 (GB) ..... 0025017

An optical autocorrelator comprises an optical waveguide (40) of semiconductor material which exhibits two photon absorption at a wavelength at which the autocorrelator is intended to operate. Reflecting means (46) are provided at a part of the waveguide which is remote to an end (42) in which an optical pulse (44) is input for reflecting the optical pulse such as to generate counter-propagating optical pulses in the waveguide. A plurality of electrodes (48<sub>1</sub>-48<sub>N</sub>) are disposed along the waveguide for measuring a two photon absorption photocurrent (i<sub>1</sub>-i<sub>n</sub>) generated in the waveguide by the counter-propagating optical pulses.

(51) **Int. Cl.**<sup>7</sup> ..... **G01B 9/02**

(52) **U.S. Cl.** ..... **356/450**

(58) **Field of Search** ..... 356/450

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**9 Claims, 6 Drawing Sheets**

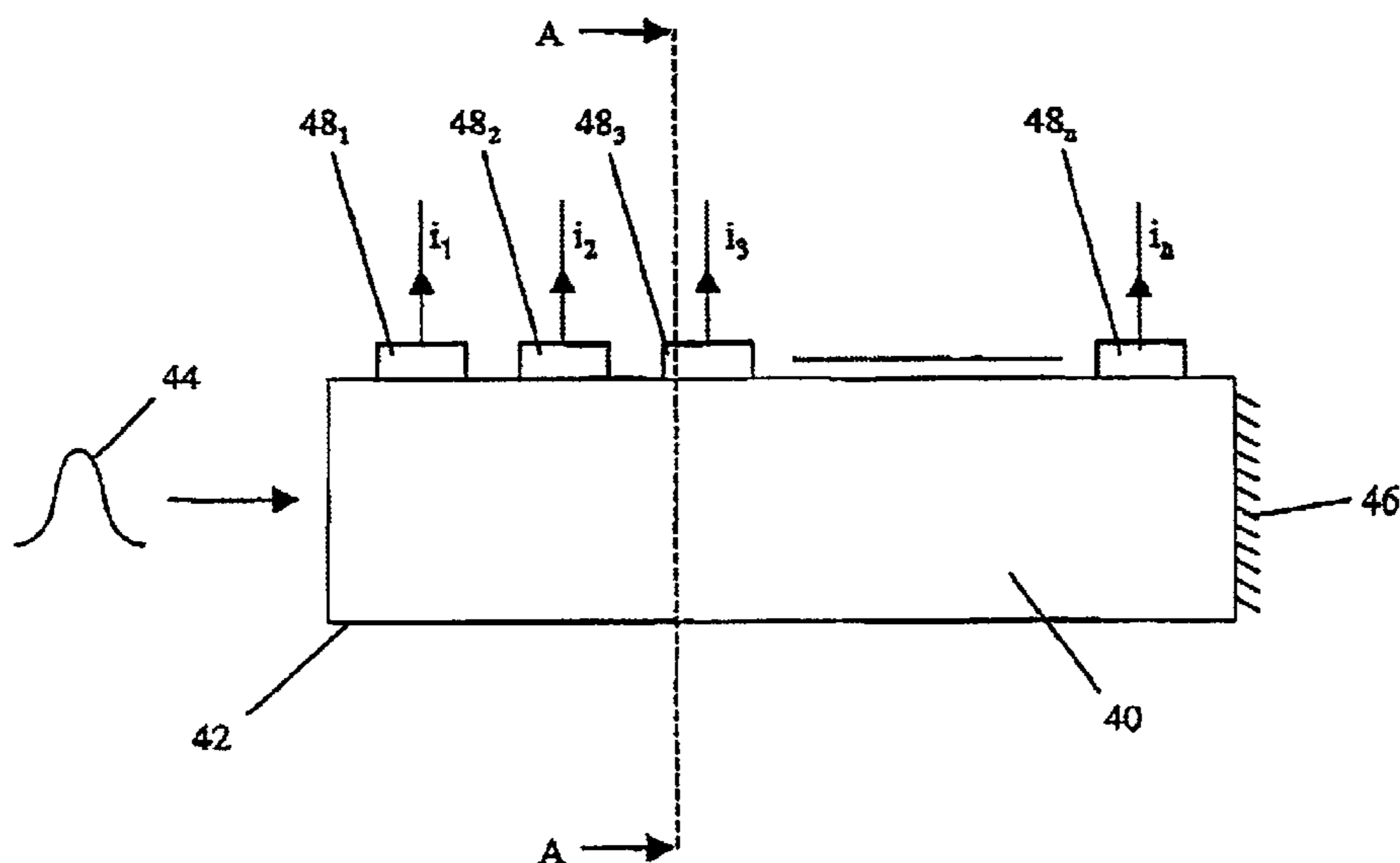


Fig. 1  
(Prior Art)

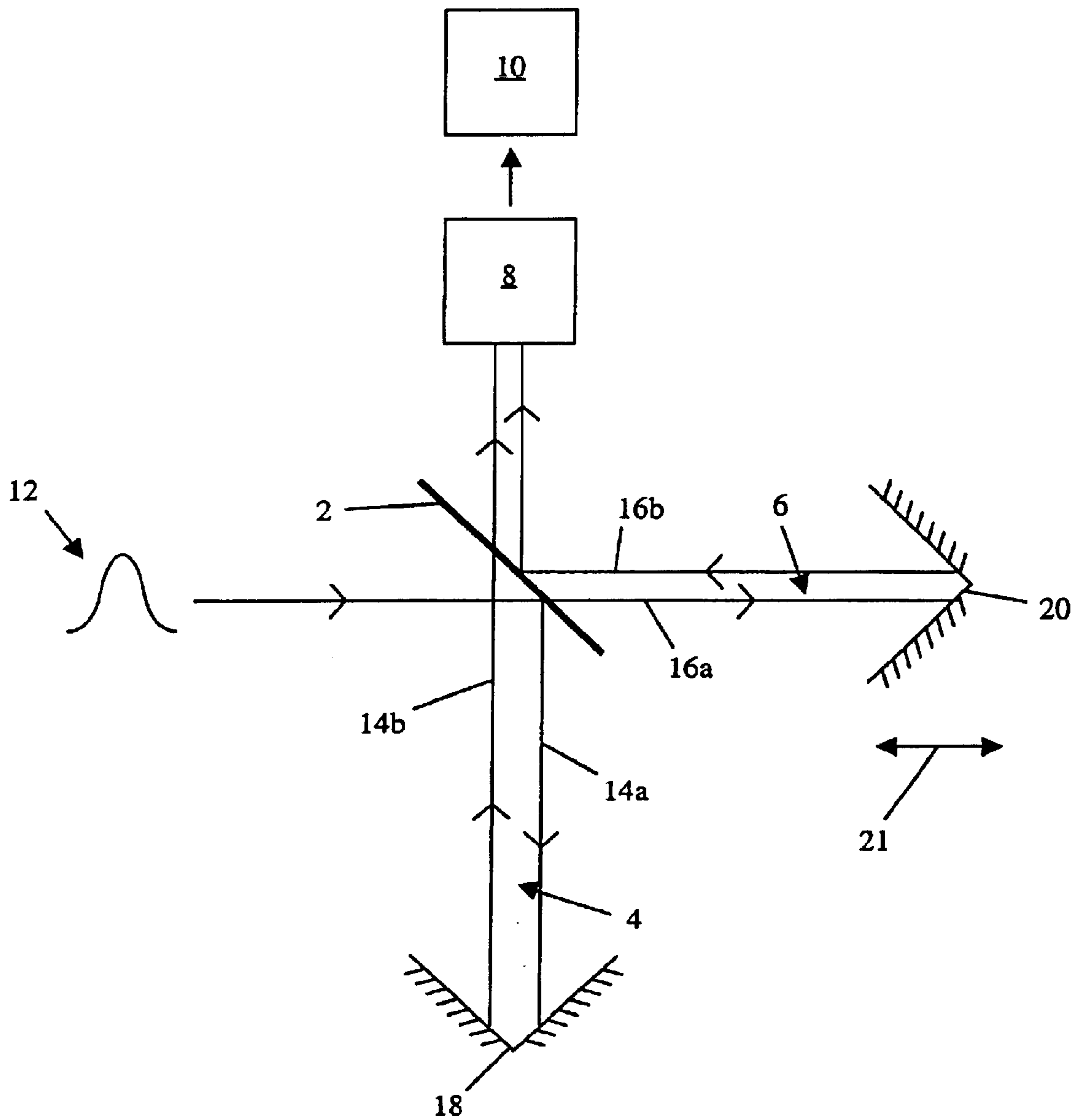


Fig. 2

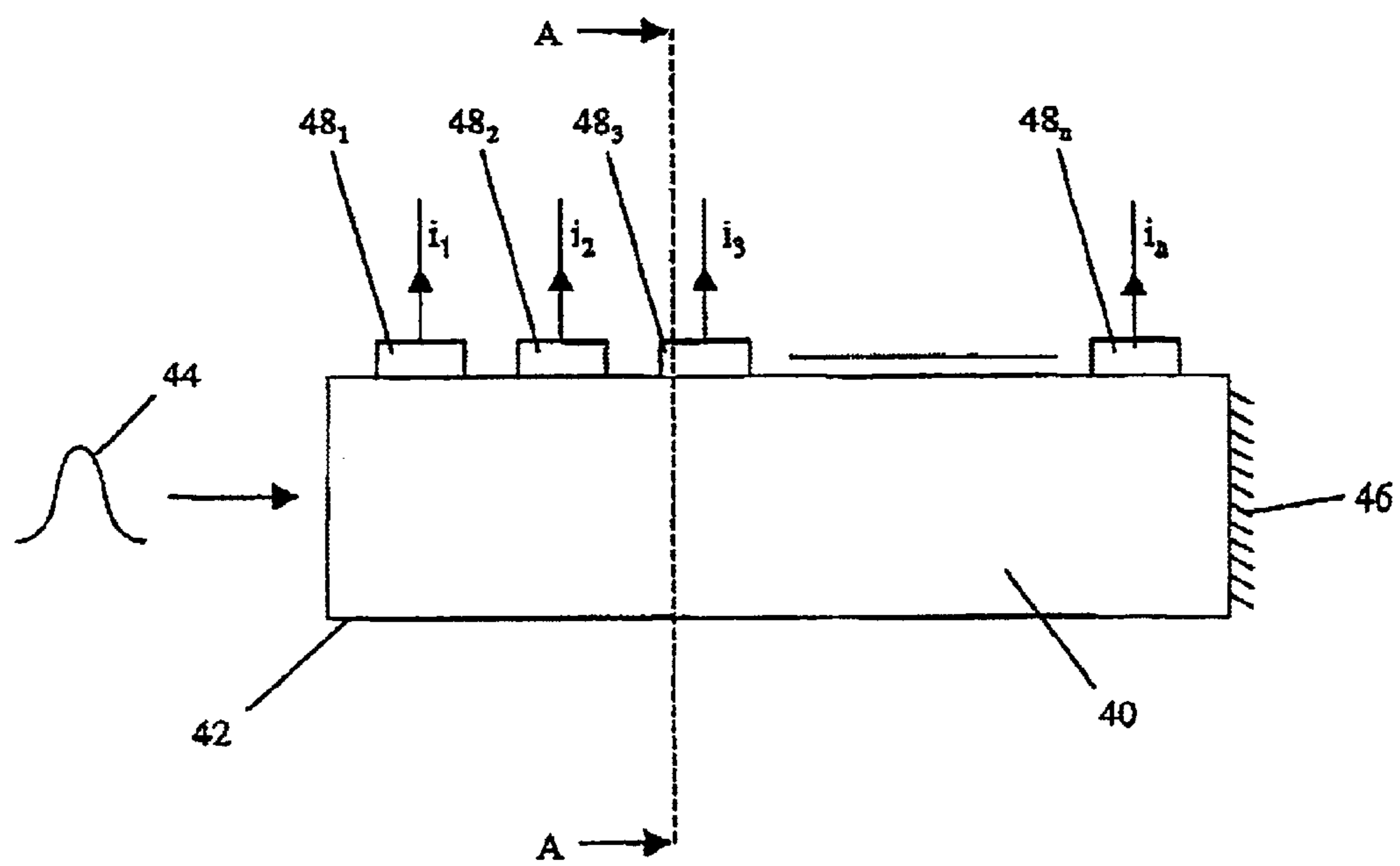
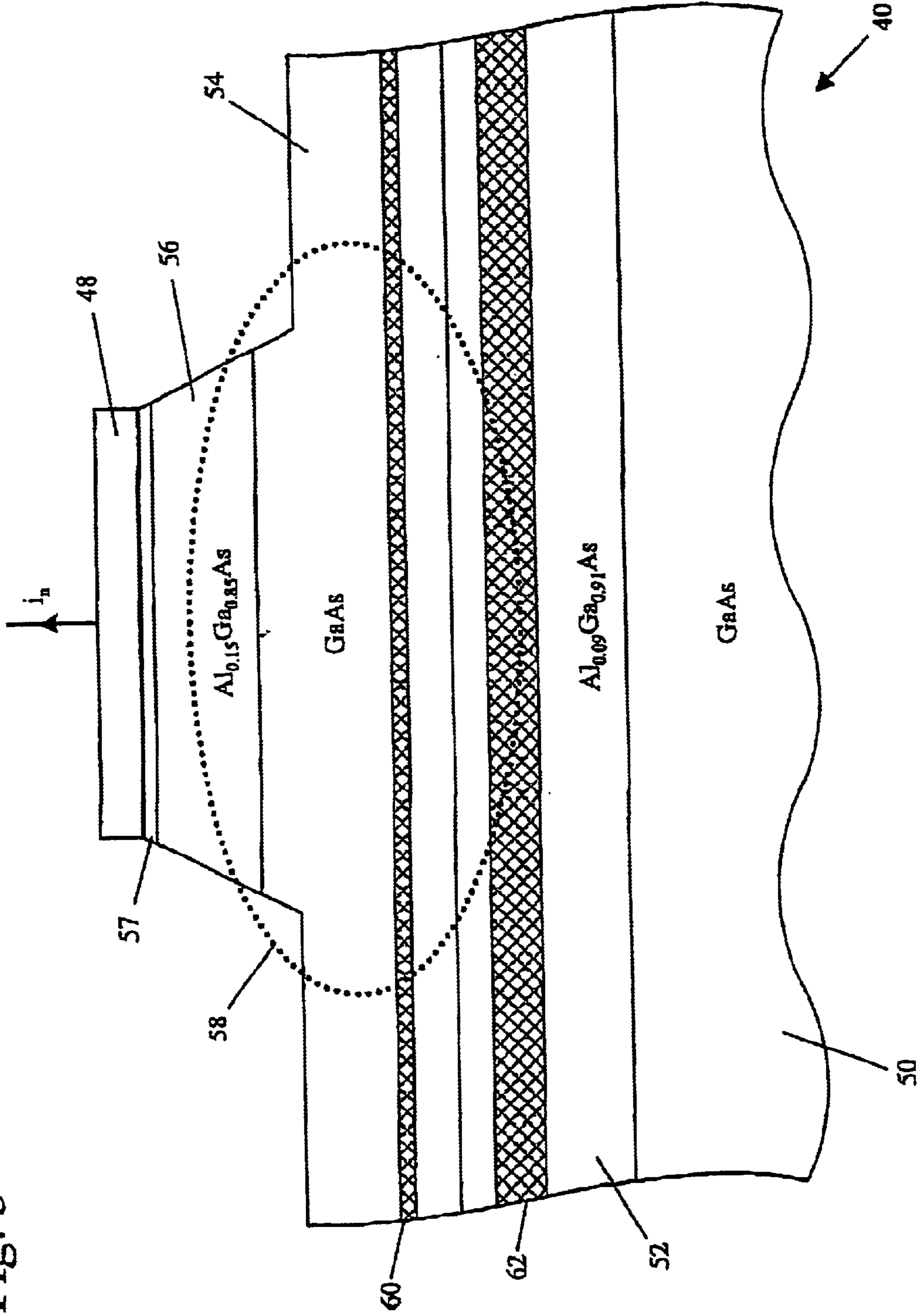


Fig. 3



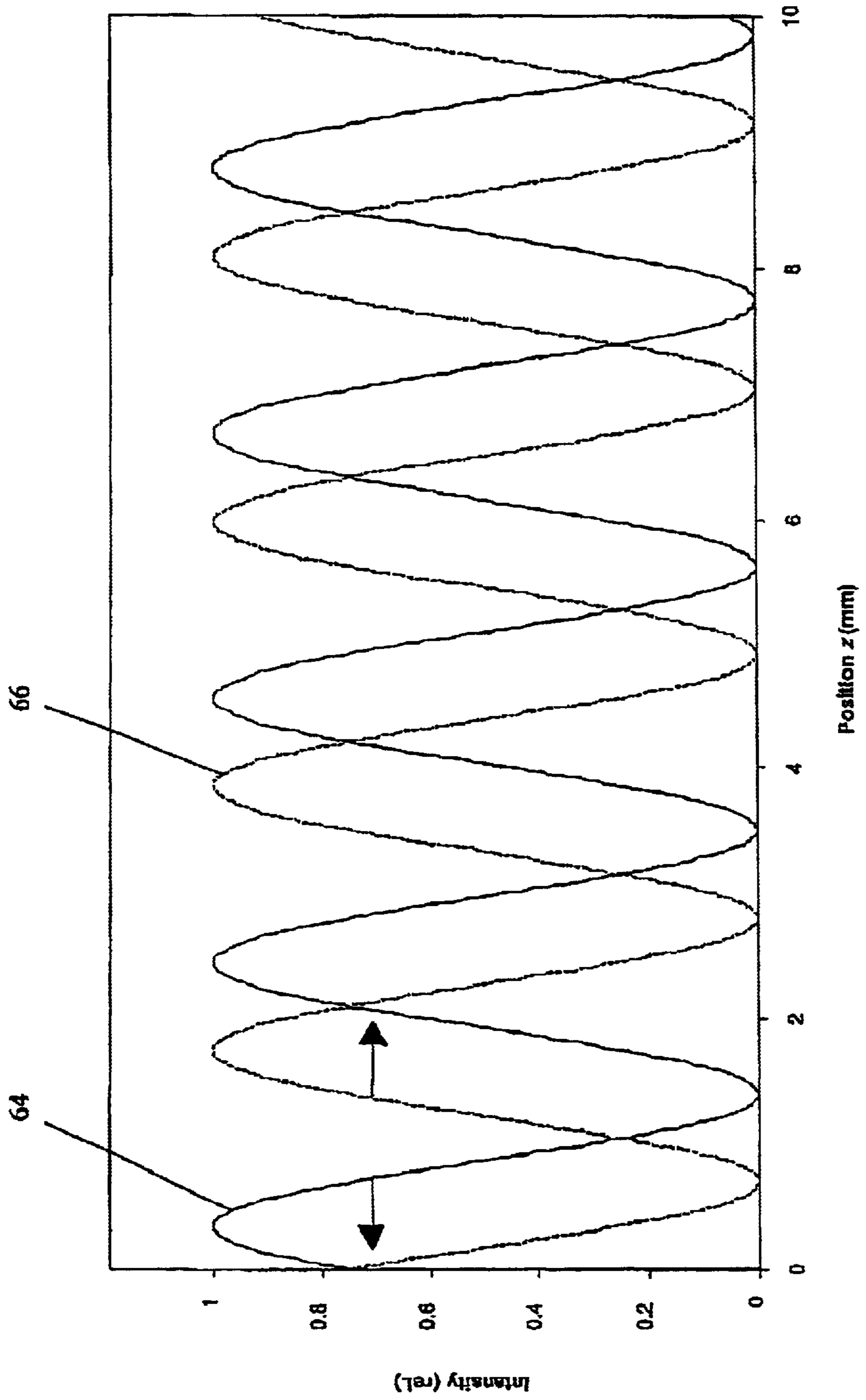


Fig. 4

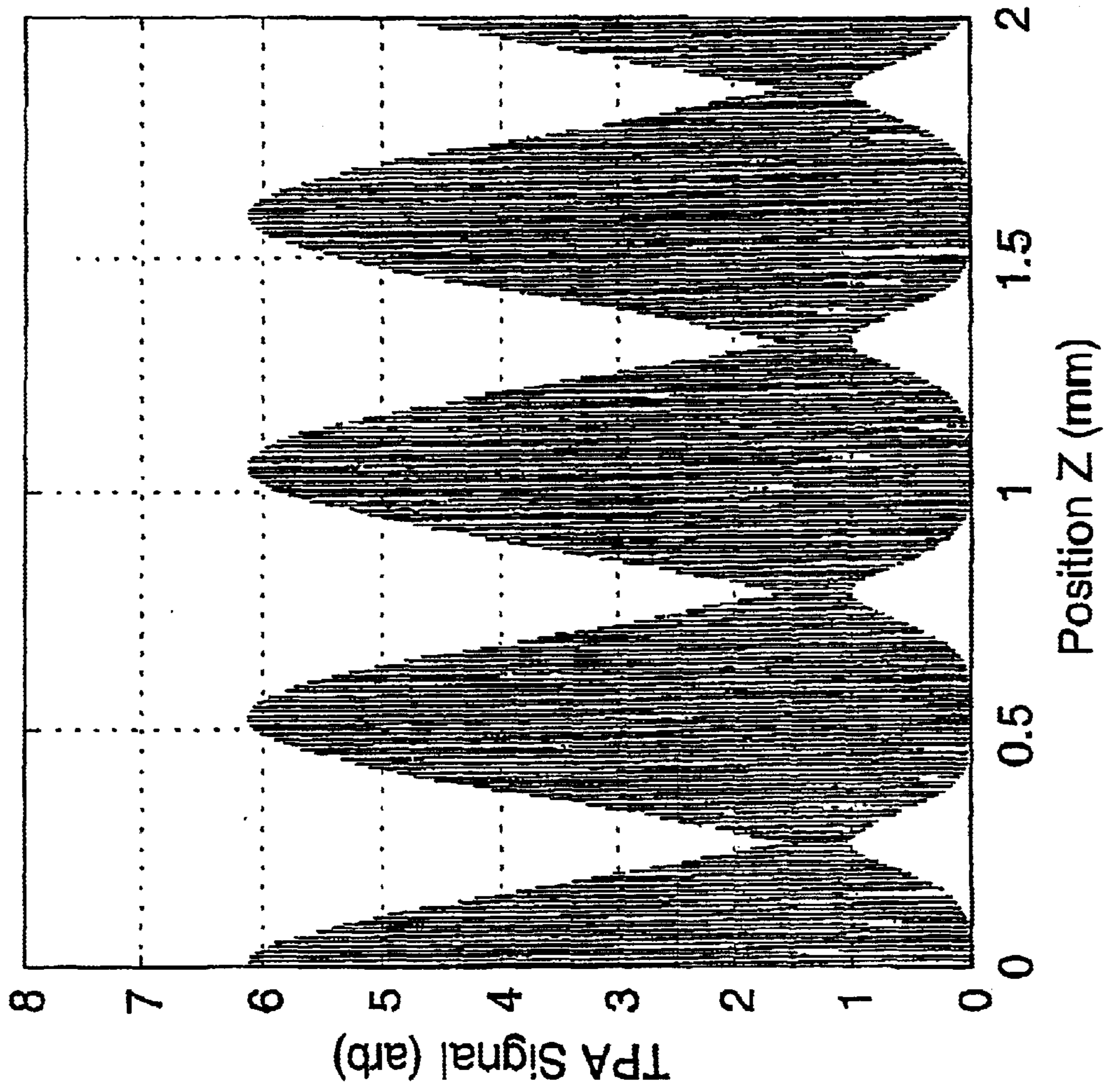
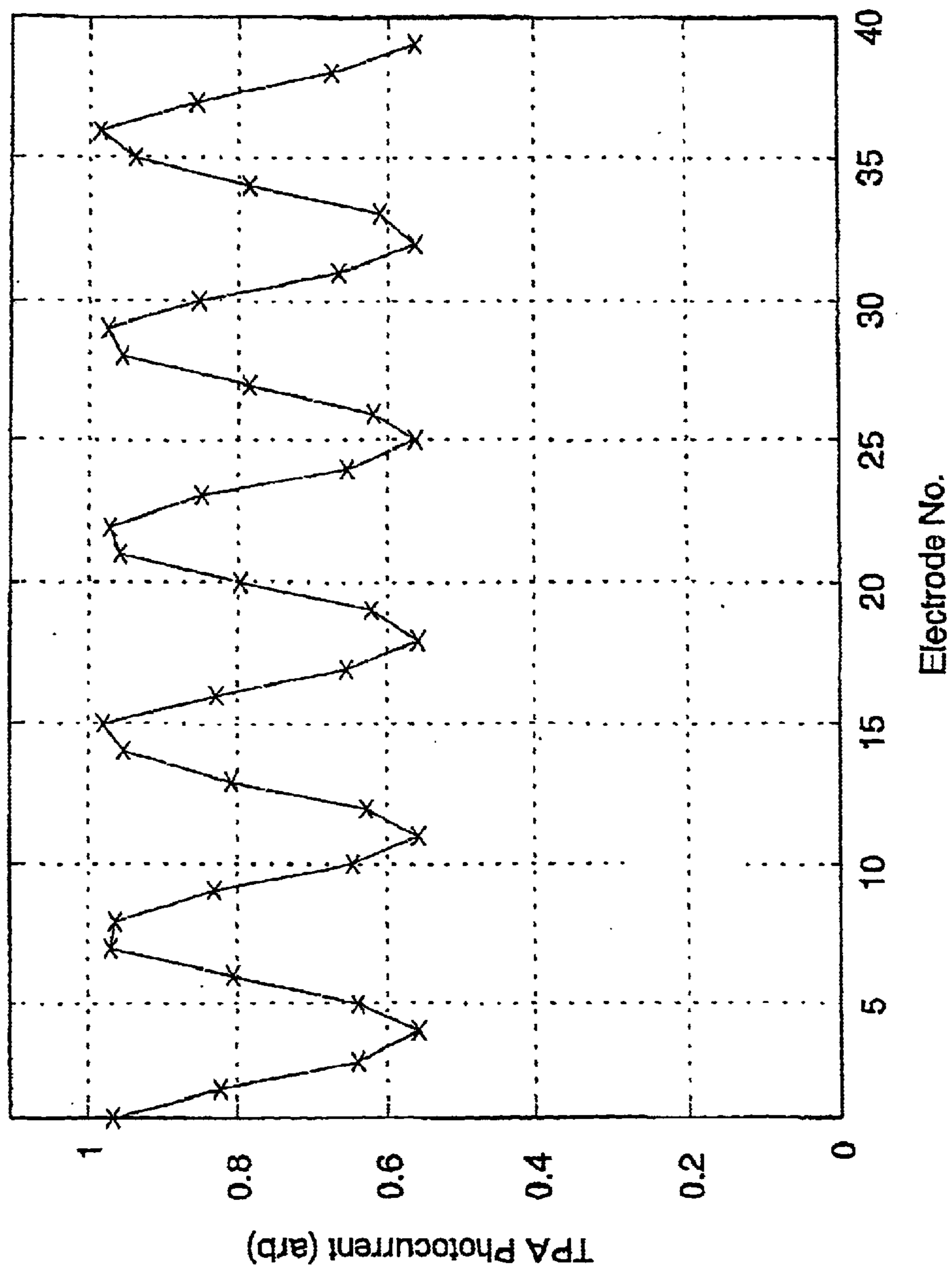


Fig. 5

Fig. 6



## OPTICAL AUTOCORRELATOR

## RELATED APPLICATIONS

This application is a 35 U.S.C. 371 national stage filing of International Application No. PCT/GB01/04558, filed 12 Oct. 2001, which claims priority to Great Britain Patent Application No. 0025017.5, filed on 12 Oct. 2000 in Great Britain. The contents of the aforementioned applications are hereby incorporated by reference.

## BACKGROUND OF THE INVENTION

This invention relates to an optical autocorrelator and more especially to such a device based on two-photon absorption.

Optical autocorrelators are used for monitoring the width and shape of very short duration optical pulses, i.e. pulse-widths down to a few femtoseconds. Optical autocorrelators are potentially very useful in high data rate optical communication systems (those operating at  $\geq 40$  Gbit/sec) where they could be used for monitoring pulse quality and timing jitter in data bit interleaved systems.

Referring to FIG. 1 there is shown a schematic representation of a known optical autocorrelator arrangement which comprises an optical splitter **2**, a reference path **4**, a variable path delay **6**, a non-linear mixing medium **8** and an optical detector **10**. An input optical pulse **12** is split by the optical splitter **2** into two signals, sometimes termed channels, **14a**, **16a** which respectively pass along the reference path **4** and variable path delay **6**. Typically the reference path **4** comprises a fixed retro-reflector **18** whilst the variable path delay **6** comprises a moveable retro-reflector **20** which is mounted on a mechanically oscillating stage, such as a loudspeaker. Movement of the retro-reflector **20** is indicated by a double headed arrow **21**. The two optical signals **14a** **16a** are reflected by their respective reflectors **18**, **20** and the reflected signals **14b**, **16b** are mixed together in the non-linear mixing medium **8** to produce a non-linear mixing product which is detected by the optical detector **10**. The detected signal is plotted as a function of relative path delay between the two channels and represents an autocorrelation trace of the input optical pulse **12** which can be related to the input pulse-width and shape.

Typically the non-linear mixing element **8** exploits second-harmonic generation (SHG), but other non-linear mixing elements have been proposed which use processes such as two-photon fluorescence (TPF) and two-photon absorption (TPA).

TPA is a non-resonant, non-linear optical process that is observed for photons with energy less than the semiconductor band-gap  $E_g$ , but greater than  $E_g/2$ . The process occurs when an electron is excited from the valence to the conduction band via an intermediate virtual state and thus requires two photons. This intermediate state can be any state in any band, although the transition probability is highest when the energy difference between the states involved is smallest; that is, when the intermediate state lies closest to the upper valence band or lower conduction band. One example of a combined mixing and detector element is an AlGaAs/GaAs optical waveguide having a pair of electrodes on the waveguide to measure the photocurrent generated in the waveguide by the two optical signals.

A disadvantage of this type of optical autocorrelator is the difficulty of integrating the moveable reflector, optical splitter and non-linear mixing element.

Optical autocorrelators have also been proposed which rely upon surface-emitting second-harmonic generators

(SESHG). An SESHG autocorrelator comprises a waveguide into which identical optical signals are input into opposite ends of the waveguide such as to generate counter-propagating signals. As a result of the counter-propagating waves these generate, via the second-order optical non-linearity of the waveguide material, a second-harmonic (SH) signal that is emitted from the surface of the waveguide in a direction normal to its axis. The spatial distribution of the surface-emitted SH signal along the waveguide constitutes an autocorrelation trace and this is typically imaged onto a charged-coupled device (CCD) camera using bulk optics. It has been further proposed to monolithically integrate an array of photodiodes along the length of the waveguide. To eliminate the need to generate the identical input signals it has been proposed to input a single optical signal into one end of the waveguide and rely on reflection from the opposite end facet to generate the counter-propagating optical signal.

It has also been demonstrated to couple identical signals into opposite ends of the p-i-n waveguide such that they counter-propagate. Such an arrangement eliminates the need for a variable path delay thereby making it possible to fabricate the autocorrelator as an integrated device.

## SUMMARY OF THE INVENTION

The present invention has arisen in an endeavour to provide an optical autocorrelator which in part at least alleviates the limitations of the known arrangements.

According to the invention an optical autocorrelator comprises: an optical waveguide of semiconductor material which exhibits two photon absorption at a wavelength at which the autocorrelator is intended to operate; reflecting means associated with a part of the waveguide which is remote to an end in which an optical pulse is input, said reflecting means for reflecting the optical pulse such as to generate counter-propagating optical pulses in the waveguide and a plurality of electrodes disposed along the waveguide for measuring a two photon absorption photocurrent generated in the waveguide by the counter-propagating optical pulses.

Preferably the reflecting means comprises an end facet of the waveguide which can be formed by cleaving or etching of the waveguide. Alternatively the reflecting means comprises a grating structure defined in the waveguide such as a Bragg grating.

To assist in coupling the input optical pulse into the waveguide the autocorrelator preferably further comprises an anti-reflection coating on the end of the waveguide into which the optical pulse is input.

Preferably the electrodes are located at equal intervals along the waveguide such that the photocurrents represent substantially equal time samples. For ease of fabrication the electrodes advantageously form a Schottky contact with the waveguide.

In a particularly preferred implementation the waveguide comprises GaAlAs/GaAs structure though other III-V semiconductor material structures can be utilised.

Advantageously the optical autocorrelator further comprises an optical modulator which is monolithically integrated with the autocorrelator for selectively modulating the intensity of the optical pulse before it is input into the waveguide. Such an arrangement is particularly advantageous for calibrating the autocorrelator.

## BRIEF DESCRIPTION OF THE DRAWINGS

In order that the invention can be better understood an optical autocorrelator in accordance with the invention will



now be described by way of reference to the accompanying drawings in which:

FIG. 1 is a schematic representation of a known optical autocorrelator;

FIG. 2 is a schematic representation of an optical autocorrelator in accordance with the invention;

FIG. 3 is a cross-sectional view of the waveguide structure of the optical autocorrelator of FIG. 2 in a direction along the optical axis of the waveguide;

FIG. 4 is a plot of optical intensity versus position along the waveguide;

FIG. 5 is a plot of calculated photocurrent versus position along the waveguide; and

FIG. 6 is a plot of photocurrent versus electrode.

#### DESCRIPTION OF ILLUSTRATED EMBODIMENT

Referring to FIG. 2 there is shown an optical autocorrelator in accordance with the invention which is for measuring the pulse widths of an optical pulse (data) train **44** with a pulse repetition rate of 40 Gbits<sup>-1</sup> and a wavelength of 1550 nm (communications band). The autocorrelator comprises an AlGaAs/GaAs optical waveguide **40** having a first optical input end **42** which is anti-reflection coated to maximise coupling of the optical pulse train **44** into the waveguide and an opposite end having a high reflection coating **46** on its end facet. Located on a top surface of and disposed along the length of the optical axis of the waveguide **40** is a plurality (n) of electrodes **48<sub>1</sub>–48<sub>n</sub>**, which are used to detect a respective photocurrent  $i_1$ – $i_n$  generated through two photon absorption in the region of the waveguide underlying the electrode. In the embodiment illustrated the electrodes are equally spaced at a 75  $\mu\text{m}$  interval along the waveguide such that the photocurrents  $i_1$ – $i_n$  represent samples which are substantially equally spaced in time, though it will be appreciated that the electrodes can be spaced in other ways. Each electrode **48<sub>1</sub>–48<sub>n</sub>** forms a Schottky contact with the waveguide. It will further be appreciated that the bandgap of the waveguide material is chosen such that linear absorption is minimal.

Referring to FIG. 3 there is shown a cross section through the line “AA” of FIG. 2 of the waveguide structure. The waveguide **40** comprises a rib loaded waveguide structure comprising in order, a semi-insulating gallium arsenide (GaAs) substrate **50**, a 3.1  $\mu\text{m}$  thick aluminium gallium arsenide (Al<sub>0.09</sub>Ga<sub>0.91</sub>As) layer **52**, a 1.95  $\mu\text{m}$  thick GaAs optical guiding layer **54**, a further aluminium gallium arsenide (Al<sub>0.15</sub>Ga<sub>0.85</sub>As) layer **56** of 0.85  $\mu\text{m}$  thickness, a 25 nm GaAs thick capping layer **57** and the electrode **48** which typically comprises aluminium on top of a thin titanium bonding layer (Ti:Al). The layer **54** provides the optical waveguide medium with the refractive index contrast between the AlGaAs layers **52** and **56** and layer **54** provides vertical confinement of light thereby constraining light to propagate substantially within the layer **54**. Lateral confinement of light is provided by the AlGaAs layer which is selectively etched to define a mesa (plateau region) which provides an in-plane effective refractive index contrast that confines light to propagate in an optical mode below the mesa as illustrated by line **58** in FIG. 3. Typically the mesa is approximately 5  $\mu\text{m}$  in width at its base and has been etched into the GaAs layer **54** such that it has an overall height of 1.2–1.3  $\mu\text{m}$ .

Within the optical guiding layer **54** an n-doped layer **60** is provided to act as a depletion stop layer. A depletion region

is formed between the top Schottky contact **48** and the n-doped depletion stop layer **60** such that the waveguide constitutes a photodiode. An n-doped conductive layer **62** is provided within Al<sub>0.09</sub>Ga<sub>0.91</sub>As layer **52** and constitutes a buried backplane electrode to the photodiode. Electrical connection to the conductive layer is facilitated using a large area Schottky contact which is located elsewhere on the structure and is not shown in the Figure. To minimise free-carrier optical loss the n-doped conductive layer **62** is at sufficient distance from the optical guiding layer **54** to minimise strong overlap of the optical mode **58** of the guided pulse with the layer **62**. Externally the electrodes **48** and contact are electrically biased such that the large area contact is forward biased thus resulting in a reverse biased waveguide photodiode.

It will be appreciated therefore that the autocorrelator of the present invention thus comprises a plurality of photodiodes which are disposed along the optical axis of the waveguide. In operation the optical input pulse **44** is applied to the input end **42** of the waveguide, propagates along the waveguide and is reflected by the end **46** of the waveguide such as to generate a counter-propagating optical pulse to that of the input pulse. The plurality of electrodes **48<sub>1</sub>–48<sub>n</sub>** detect, at selected points along the waveguide’s length, the photocurrent generated in the waveguide by the counter-propagating pulses. A plot of these currents versus position thus represents an autocorrelation of the input optical pulse.

Since TPA is an ultrafast process such that the absorption is instantaneously dependent on optical intensity, i.e. the probability of a TPA event occurring is proportional to the optical intensity, the total number of TPA events that occur per unit time or unit length of waveguide is therefore proportional to the square of the intensity.

Referring to FIG. 4 there is shown a plot of optical intensity versus position along the waveguide for a train of raised cosine pulses having a 40 GHz repetition rate. It is to be noted that in this Figure the position designated zero corresponds to the reflecting end **46** of the waveguide. The input optical pulse train is designated **64** and the reflected counter-propagating pulse train indicated as a dashed line **66**. It can be shown that the optical amplitudes  $E_1(z)$  and  $E_2(z)$  of the input and reflected pulses respectively as a function of distance  $z$  along the waveguide is given by:

$$E_1(z) = \hat{E}_1(z) \cos(\omega_0 t - kz) \quad (1)$$

$$E_2(z) = \hat{E}_2(z) \cos(\omega_0 t + kz) \quad (2)$$

where  $\hat{E}_1$  and  $\hat{E}_2$  are the pulse envelopes of the input and reflected waves,  $\omega_0$  is the optical frequency,  $t$  is time,  $k$  is the waveguide propagation constant, and  $z$  is the propagation distance. The optical intensity within the waveguide as a function of distance along the waveguide,  $I(z)$ , is proportional to

$$I(z) \propto |E_1(z) + E_2(z)|^2. \quad (3)$$

As discussed above the total number of TPA events and hence two-photon photocurrent,  $i_{tpa}(z)$  is proportional to the square of the intensity. Therefore

$$i_{tpa}(z) \propto |E_1(z) + E_2(z)|^4. \quad (4)$$

This photocurrent distribution will effectively be an autocorrelation trace of the input pulse where the fast temporal dependence of the input pulses is converted to a spatial dependence ( $z$ ) which can be time averaged and sampled by the array of Schottky contact photodiodes through the generation of the photocurrents  $i_1$  to  $i_n$ .

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The spatial resolution of the autocorrelator is defined by the size of the electrodes **48** (which will typically be tens of  $\mu\text{m}$ ) and will, therefore, be much coarser than the optical standing-wave which is typically sub-micron. Thus the photocurrent from each of the electrodes will be a spatial average over many optical wavelengths. The temporal resolution,  $t_{res}$ , is related to the spatial resolution,  $z_{res}$  (the electrode spacing), by the relationship:

$$t_{res} = \frac{n_g}{c} z_{res} \quad (5)$$

where  $n_g$  is the group index of the waveguide and  $c$  is the speed of light in vacuo.

Referring to FIG. **5** there is shown a plot of calculated two-photon photocurrent versus position along the waveguide for a 40 GHz repetition rate pulse train. As can be clearly seen from this Figure the optical standing-wave pattern is on the sub-micron scale. Referring to FIG. **6** this shows the photocurrent distribution versus electrode number for an autocorrelator having forty electrodes which are spaced on a 75  $\mu\text{m}$  pitch for a 40 GHz repetition rate pulse train. As can be seen from the Figure the fine standing-wave pattern is now lost leaving an autocorrelation trace (with background) with a peak to background contrast ratio of 1.75. For peak optical input powers of  $\sim 10$  mW two-photon photocurrent levels of 0.1–1.0  $\mu\text{A}$  are expected at the autocorrelation peaks using 75  $\mu\text{m}$  pitch electrodes.

A particular advantage of the optical autocorrelator of the present invention is that it can be readily monolithically integrated with other photonic components such as optical modulators, couplers, splitters, two-photon power monitors, etc. In one embodiment it is envisaged to fabricate the autocorrelator with a monolithically integrated optical modulator in front of it. This would allow intensity modulation of the input to the autocorrelator thus facilitating lock-in detection of the autocorrelation trace in order to filter out noise and remove any d.c. signal components due to parasitic leakage currents within the structure. Modulation of the input optical pulse could also be used to determine the relationship between autocorrelation signal and input light level thus permitting extraction of the desired second-order (autocorrelation) signal from any linear signal component that may be present e.g. due to carrier generation via energy levels associated with defects in the semiconductor material.

Although the present invention has been described in detail in relation to the specific embodiment, it will be appreciated that changes, substitutions and variations can be

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made which are within the scope of the invention. For example whilst, for convenience, the end facet of the waveguide is used to reflect the optical pulse to generate the counter-propagating optical pulse, other reflecting means can be utilised such as etching a facet at a point along the waveguide which is distal to the input facet or by incorporating a reflecting structure within the waveguide such as a Bragg grating defined in the layer **56**.

What is claimed is:

**1.** An optical autocorrelator comprising: an optical waveguide of semiconductor material which exhibits two photon absorption at a wavelength at which the autocorrelator is intended to operate; reflecting means associated with a part of the waveguide which is remote to an end in which an optical pulse is input, said reflecting means for reflecting the optical pulse such as to generate counter-propagating optical pulses in the waveguide and a plurality of electrodes disposed along the waveguide for measuring a two photon absorption photocurrent generated in the waveguide by the counter-propagating optical pulses.

**2.** An optical autocorrelator according to claim **1** in which the reflecting means comprises an end facet of the waveguide.

**3.** An optical autocorrelator according to claim **1** in which the reflecting means comprises a grating defined in the waveguide.

**4.** An optical autocorrelator according to claim **3** in which the grating comprises a Bragg grating.

**5.** An optical autocorrelator according to claim **1** further comprising an anti-reflection coating on the end of the waveguide into which the optical pulse is input.

**6.** An optical autocorrelator according claim **1** in which the plurality of electrodes are located at equal intervals along the waveguide.

**7.** An optical autocorrelator according to claim **1** in which the electrodes form a Schottky contact with the waveguide.

**8.** An optical autocorrelator according to claim **1** in which the waveguide comprises GaAlAs/GaAs structure.

**9.** An optical autocorrelator according to claim **1** further comprising an optical modulator which is monolithically integrated with the autocorrelator for selectively modulating the intensity of the optical pulse before it is input into the waveguide.

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